

TSM4416

30V N-Channel MOSFET



Pin Definition: 1. Source 2. Source 3. Source 4. Gate 5, 6, 7, 8. Drain

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A)
30	19 @ V _{GS} = 10V	8.5
	28 @ V _{GS} = 4.5V	6

Features

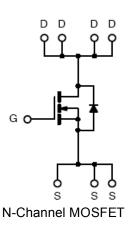
- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PWM Application

Ordering Information

Part No.	Package	Packing
TSM4416CS RL	SOP-8	2.5Kpcs / 13" Reel



Block Diagram

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V _{GS}	20	V
Continuous Drain Current		I _D	8.5	А
Pulsed Drain Current		I _{DM}	40	А
Continuous Source Current (Diode Conduction) ^{a,b}		ls	2.6	А
Maximum Power Dissipation	Ta = 25°C	– P _D	2.5	W
	Ta = 75°C		1.6	
Operating Junction Temperature		TJ	+150	°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	RƏ _{JF}	25	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	RƏ _{JA}	50	°C/W

Notes:

a. Pulse width limited by the Maximum junction temperature

b. Surface Mounted on FR4 Board, t \leq 10 sec.



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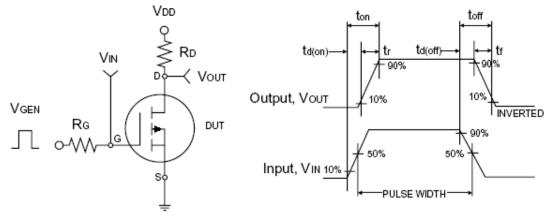
Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Мах	Unit
Static		1				
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = 250uA$	BV _{DSS}	30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	V _{GS(TH)}	1	1.8	3	V
Gate Body Leakage	V_{GS} = ±20V, V_{DS} = 0V	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 24V, V_{GS} = 0V$	I _{DSS}			-1.0	μA
On-State Drain Current ^a	V _{DS} ≥ 5V, V _{GS} = 10V	I _{D(ON)}	40			А
Drain-Source On-State Resistance ^a	V_{GS} = 10V, I_{D} = 8.5A	Б		15.5	19	mΩ
Drain-Source On-State Resistance	V_{GS} = 4.5V, I_{D} = 6A	R _{DS(ON)}		23	28	
Forward Transconductance ^a	$V_{DS} = 5V, I_{D} = 8.5A$	g _{fs}		23		S
Diode Forward Voltage	I _S = 1A, V _{GS} = 0V	V _{SD}		0.71	1.0	V
Dynamic [♭]			-			-
Total Gate Charge	V _{DS} = 15V, I _D = 8.5A, V _{GS} = 5V	Qg		19	24	
Gate-Source Charge		Q_gs		9.36	12	nC
Gate-Drain Charge		Q _{gd}		4.2		
Input Capacitance		C _{iss}		1040		
Output Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$	C _{oss}		180		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		110		
Switching ^c						
Turn-On Delay Time		t _{d(on)}		5.2		
Turn-On Rise Time	$V_{DD} = 15V, R_L = 1.8\Omega,$	t _r		4.4		
Turn-Off Delay Time	$I_{\rm D} = 1$ A, $V_{\rm GEN} = 10$ V,	t _{d(off)}		17.3		nS
Turn-Off Fall Time	$R_{G} = 3\Omega$	t _f		3.3]

Notes:

a. pulse test: PW \leq 300µS, duty cycle \leq 2% b. For DESIGN AID ONLY, not subject to production testing.

b. Switching time is essentially independent of operating temperature.



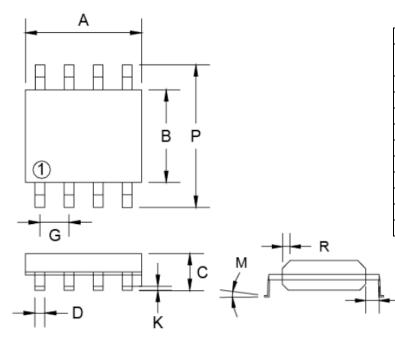
Switching Test Circuit

Switchin Waveforms



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SOP-8 Mechanical Drawing



SOP-8 DIMENSION					
DIM	MILLIMETERS		INCHES		
DIN	MIN	MAX	MIN	MAX.	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.05BSC		
К	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

Marking Diagram



- Y = Year Code
- **M** = Month Code

(A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug, I=Sep, J=Oct, K=Nov, L=Dec)

F

L = Lot Code



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